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FEATURES

■ Avalanche Rugged Technology

■ Rugged Gate Oxide Technology

■ Lower Input Capacitance

■ Improved Gate Charge

■ Extended Safe Operating Area

■ 175°C Operating Temperature

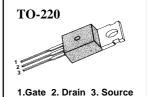
■ Lower Leakage Current : 10 μ A (Max.) @ $V_{DS} = 100V$

■ Lower $R_{DS(ON)}$: 0.092 $\Omega(Typ.)$

 $BV_{DSS} = 100 V$

 $R_{DS(on)} = 0.11 \Omega$

 $I_D = 14 A$



Absolute Maximum Ratings

Symbol	Characteristic	Value	Units	
V _{DSS}	Drain-to-Source Voltage	100	V	
	Continuous Drain Current (T _C =25 °C)		14	А
I _D	Continuous Drain Current (T _C =100°C	9.9		
I _{DM}	Drain Current-Pulsed	0	56	Α
V_{GS}	Gate-to-Source Voltage	<u>+</u> 20	٧	
E _{AS}	Single Pulsed Avalanche Energy	2	261	mJ
I _{AR}	Avalanche Current	0	14	Α
E _{AR}	Repetitive Avalanche Energy	0	5.5	mJ
dv/dt	Peak Diode Recovery dv/dt	3	6.5	V/ns
D	Total Power Dissipation (T _C =25°C)		55	W
P_{D}	Linear Derating Factor		0.36	W/°C
	Operating Junction and		FF to 147F	
T_J , T_STG	Storage Temperature Range	- 55 to +175	°C	
	Maximum Lead Temp. for Soldering		200	
T _L	Purposes, 1/8" from case for 5-seco	nds	300	

Thermal Resistance

Symbol	Characteristic	Тур.	Max.	Units			
R _{θJC}	Junction-to-Case	1	2.74				
R _{ecs}	Case-to-Sink	0.5	1	°C/W			
R _{θJA}	Junction-to-Ambient	1	62.5				

Electrical Characteristics (T_C=25°C unless otherwise specified)

Symbol	Characteristic	Min.	Тур.	Max.	Units	Test Condition	
BV _{DSS}	Drain-Source Breakdown Voltage	100		-	٧	V_{GS} =0 V , I_{D} =250 μ A	
Δ BV/ Δ T $_{ m J}$	Breakdown Voltage Temp. Coeff.		0.11		V/°C	I_D =250 μ A See Fig 7	
$V_{GS(th)}$	Gate Threshold Voltage	2.0		4.0	V	$V_{DS}=5V,I_{D}=250\mu A$	
1	Gate-Source Leakage, Forward			100	nA	V _{GS} =20V	
I _{GSS}	Gate-Source Leakage, Reverse			-100	ПА	V _{GS} =-20V	
	Duein to Course Lealing Course			10		V _{DS} =100V	
I _{DSS}	Drain-to-Source Leakage Current			100	μΑ	V_{DS} =80V, T_{C} =150°C	
В	Static Drain-Source		0	0.11	0	\/ 40\/ L 7A @	
R _{DS(on)}	On-State Resistance				Ω	$V_{GS}=10V,I_{D}=7A$	
g _{fs}	Forward Transconductance		10.25		Ω	V_{DS} =40V, I_{D} =7A ④	
C _{iss}	Input Capacitance		610	790		\/ _0\/\/ _25\/f_1MH>	
C _{oss}	Output Capacitance		150	175	pF	$V_{GS}=0V, V_{DS}=25V, f=1MHz$	
C _{rss}	Reverse Transfer Capacitance		62	72		See Fig 5	
t _{d(on)}	Turn-On Delay Time		13	40		V _{DD} =50V,I _D =14A,	
t _r	Rise Time		14	40			
t _{d(off)}	Turn-Off Delay Time		55	110	ns	$R_G=12\Omega$	
t _f	Fall Time		36	80		See Fig 13 ④⑤	
Q_g	Total Gate Charge		27	36		$V_{DS} = 80V, V_{GS} = 10V,$	
Q_gs	Gate-Source Charge		4.5		nC	I _D =14A	
Q_{gd}	Gate-Drain("Miller") Charge		12.8			See Fig 6 & Fig 12 46	

Source-Drain Diode Ratings and Characteristics

Symbol	Characteristic	Mi	n.	Тур.	Max.	Units	Test Condition
I _S	Continuous Source Current				14	Α	Integral reverse pn-diode
I _{SM}	Pulsed-Source Current (56	, A	in the MOSFET
V_{SD}	Diode Forward Voltage 4)			1.5	V	$T_J = 25$ °C, $I_S = 14A, V_{GS} = 0V$
t _{rr}	Reverse Recovery Time			109		ns	T _J =25°C,I _F =14A
Q _{rr}	Reverse Recovery Charge			0.41		¥ìC	di _F /dt=100A/μs ④

- Repetitive Rating : Pulse Width Limited by Maximum Junction Temperature
- 2 L=2mH, I_{AS} =14A, V_{DD} =25V, R_{G} =27 Ω , Starting T_{J} =25 $^{\circ}$ C
- (3) $I_{SD} \le 14A$, di/dt $\le 350A/\mu s$, $V_{DD} \le BV_{DSS}$, Starting $T_J = 25^{\circ}C$ (4) Pulse Test : Pulse Width = 250 μs , Duty Cycle $\le 2\%$
- **(5)** Essentially Independent of Operating Temperature



Fig 1. Output Characteristics

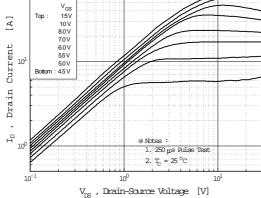


Fig 2. Transfer Characteristics

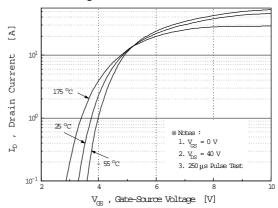


Fig 3. On-Resistance vs. Drain Current

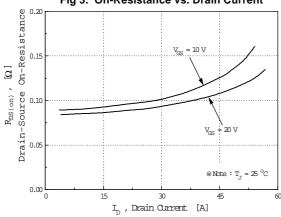


Fig 4. Source-Drain Diode Forward Voltage

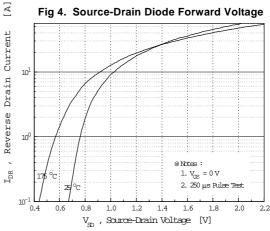


Fig 5. Capacitance vs. Drain-Source Voltage

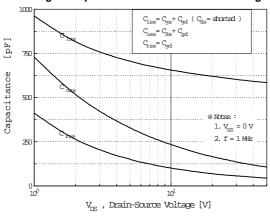
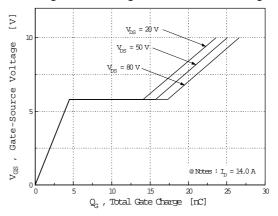
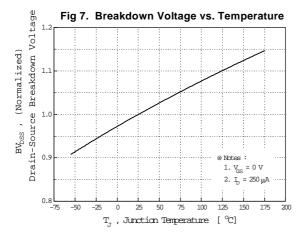


Fig 6. Gate Charge vs. Gate-Source Voltage







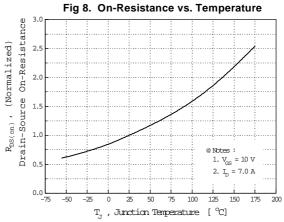
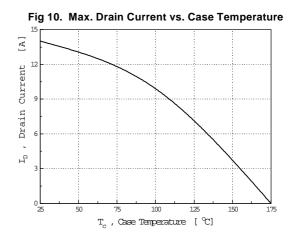


Fig 9. Max. Safe Operating Area [A] I_{D} , Drain Current 10¹ 1. T $_{\rm C}$ = 25 $^{\rm o}{\rm C}$ 2. $T_{\overline{J}}$ = 175 $^{\circ}$ C 10⁻¹

10¹ V_{DS} , Drain-Source Voltage [V]



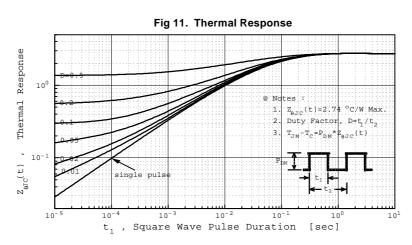




Fig 12. Gate Charge Test Circuit & Waveform

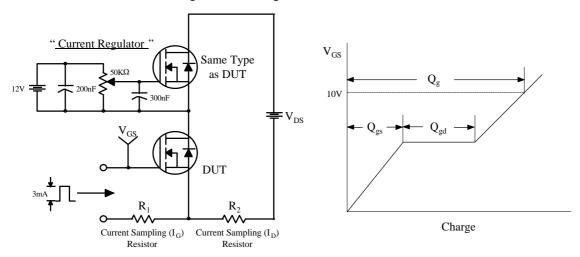


Fig 13. Resistive Switching Test Circuit & Waveforms

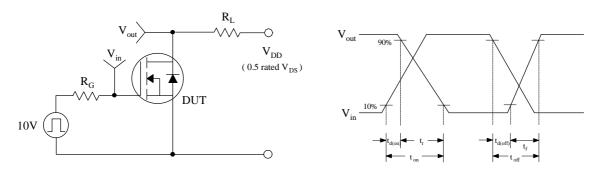


Fig 14. Unclamped Inductive Switching Test Circuit & Waveforms

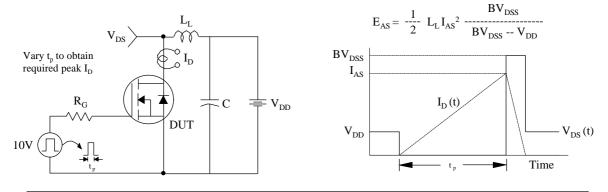
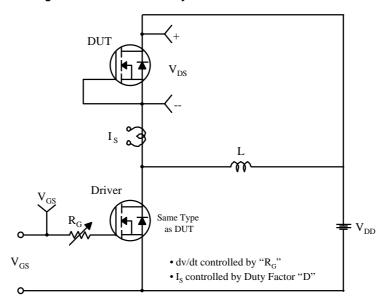
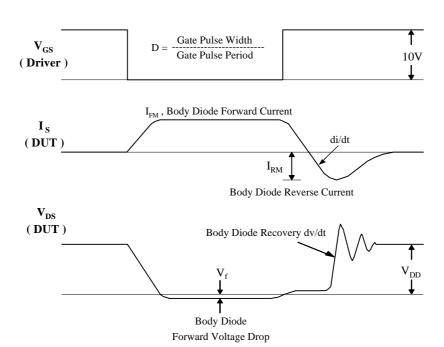


Fig 15. Peak Diode Recovery dv/dt Test Circuit & Waveforms







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